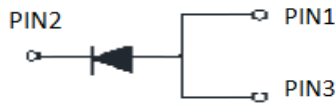
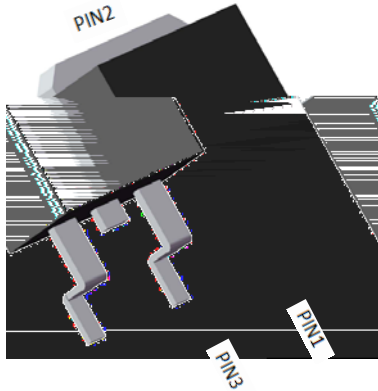


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

Package: TO-263

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102

Polarity: As marked

Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	GF3045MG
Device marking code			GF3045MG
Repetitive Peak Reverse Voltage	VRRM	V	45
Average Rectified Output Current @60Hz sine wave, R-load, T _a =25°C	I _o	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25°C	I _{FSM}	A	375
Current Squared Time @1ms t 8.3ms T _j =25°C	I ² t	A ² s	590
Storage Temperature	T _{stg}	°C	-55 ~+150
Junction Temperature IN DC Forward Mode-Forward Operations, without reverse bias, t 1 h (Fig. 1)①	T _j	°C	-55 ~+200

NOTE

- ① Meets the requirements of IEC 61215 Ed. 2 bypass diode thermal test.

Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	GF3045MG
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=30.0A	0.55
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	mA	VRM=VRRM T _a =25°C	0.5
	IRRM2		VRM=VRRM T _a =100°C	50



GF3045MG

Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	GF3045MG
Thermal Resistance	Between junction and case	R _{J-C}	°C/W	2.0

Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
GF3045MG	Approximate 1.46	50	2000	8000	Tube
GF3045MG	Approximate 1.46	1000	2000	10000	Reel

Characteristics (Typical)

FIG1: I_o -T_c Curve

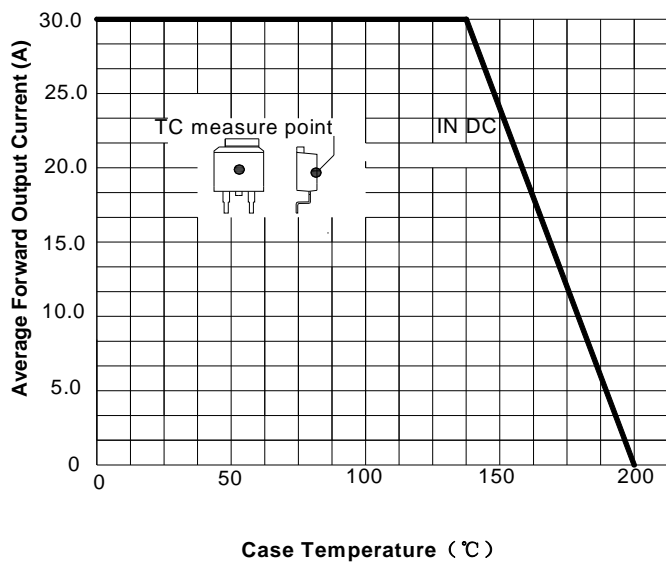


FIG2: Surge Forward Current Capability

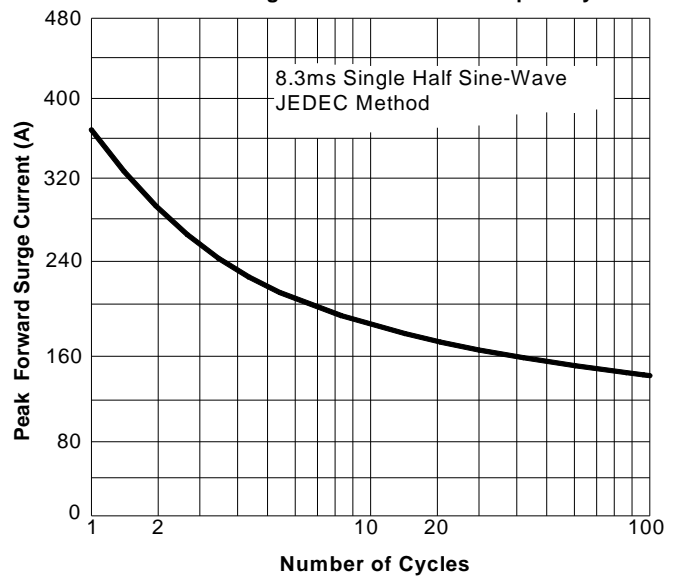


FIG3: Forward Voltage

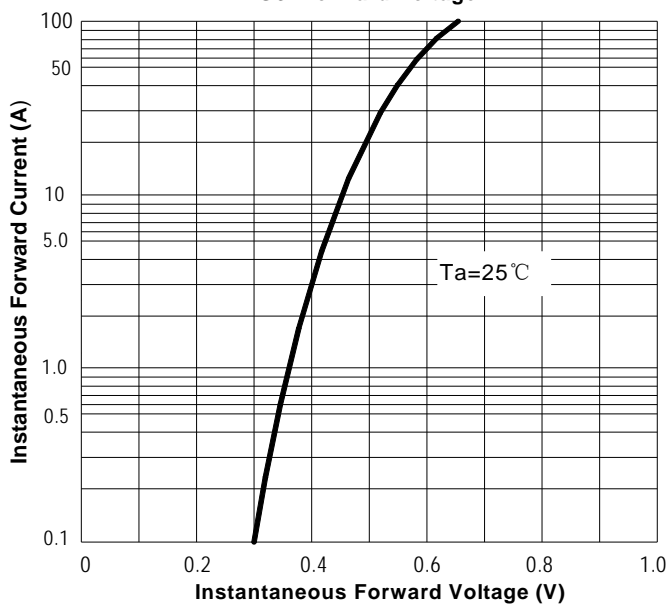
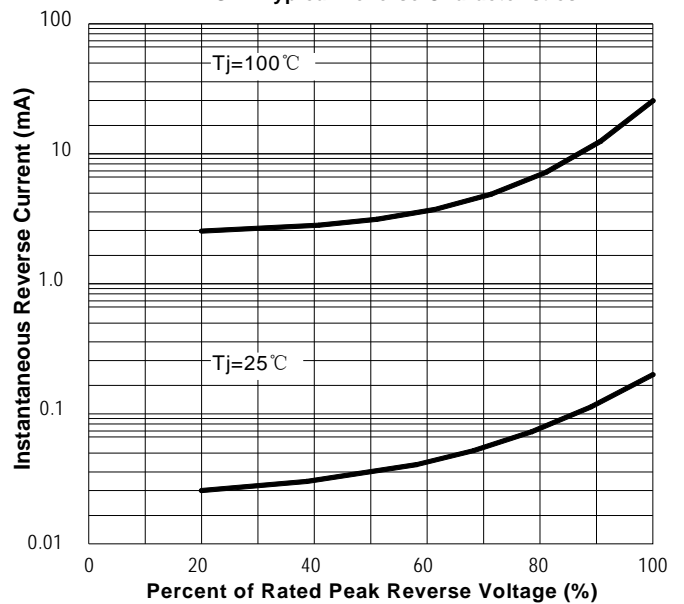
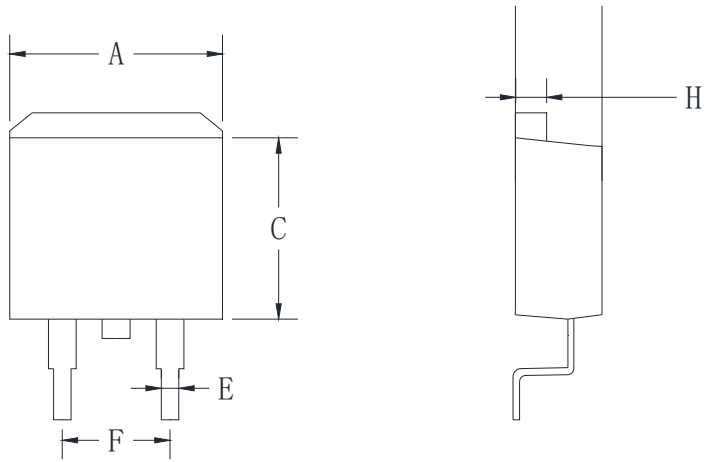


FIG4: Typical Reverse Characteristics





Outline Dimensions





GF3045MG

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